Diode Semiconductor Device - Page 1 of 1



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Inclosure I	Material:
Metal	
Overall Le	ngth:
0.360 inche	28
Terminal L	ength:
1.000 inche	95
Overall Dia	ameter:
0.150 inche	25
Mounting I	Method:
Terminal	
Features P	Provided:
Hermeticall	y sealed case
Semicond	uctor Material:
Silicon	
Voltage Ra	ting In Volts Per Characteristic:
600.0 reve	rse voltage, peak
Current Ra	ting Per Characteristic:
1.00 amper	res reverse surge current
Maximum	Operating Tempurature Per Measurement Point:
175.0 degre	ees celsius ambient air
Terminal T	ype And Quantity:
2 uninsulate	ed wire lead
Shelf Life:	
N/a	
Unit Of Me	asure:
Demilitariz	ation:
No	
Fiig:	
A110a0	